### Lecture 26

### **ANNOUNCEMENTS**

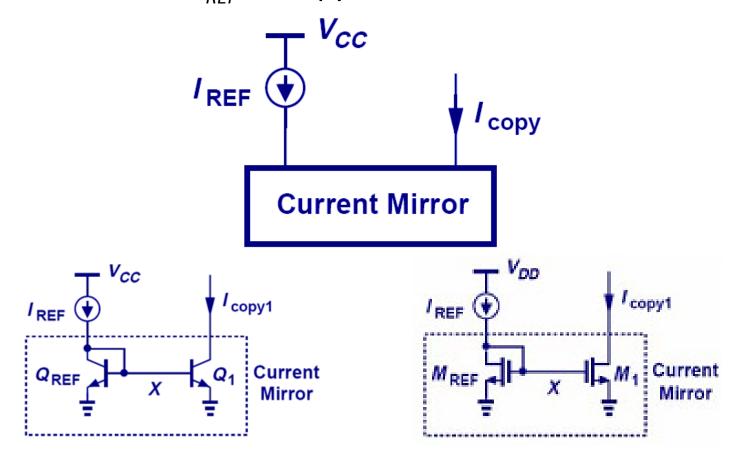
Homework 12 due Thursday, 12/6

### **OUTLINE**

- Self-biased current sources
  - BJT
  - MOSFET
- Guest lecturer Prof. Niknejad

### **Review: Current Mirrors**

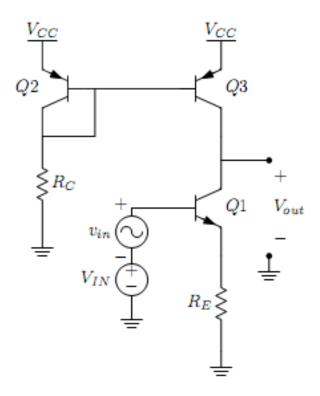
• The current mirrors we discussed require a "golden" current source,  $I_{REF}$ , to copy.



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## Review: Current Mirrors (cont'd)

- In lab 6 and lab 10, you used a resistor as your current source.
- Q: What are some problems associated with this method?



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## Review: Current Mirrors (cont'd)

• A: Variations in  $V_{CC}$  and temperature cause significant variations in  $I_{REF}$ . Consider the following analysis (ignoring base currents and the Early effect):  $V_{CC}$ 

$$I_{REF} = I_S e^{V_{BE}/V_T}$$
 $V_{BE} = V_{CC} - I_{REF} R_{REF}$ 
 $I_{REF} = I_S e^{(V_{CC} - I_{REF} R_{REF})/V_T}$ 
 $V_{CC} = 5 \text{ V}, R_{REF} = 5 \text{ k}\Omega, I_S = 1 \text{ fA}$ 
 $\Rightarrow I_{REF} = 857 \text{ }\mu\text{A}$ 
 $V'_{CC} = 4.5 \text{ V}$ 
 $\Rightarrow I'_{REF} = 758 \text{ }\mu\text{A}$ 

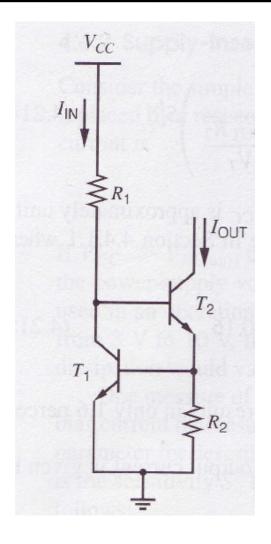
• Thus, a 10 % change in  $V_{CC}$  results in a 11.6 % change in  $I_{REF}$ .

## **Base-emitter Reference**

- Rather than having a source dependent on  $V_{cc}$ , why not use some other reference?
- For example, a  $V_{BE}$  referenced current source.
- Ignoring base currents, we have:

$$V_{BE1} = V_T \ln \frac{I_{IN}}{I_{S1}}$$
$$I_{OUT} = \frac{V_{BE1}}{R_2}$$

Q: Why is this less supply dependent?



## Base-emitter Reference (cont'd)

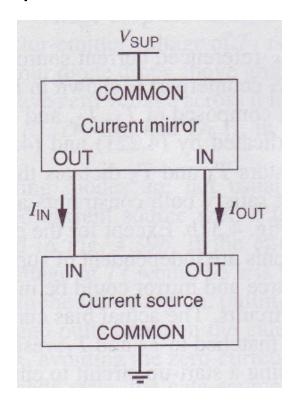
- A: Although  $I_{IN}$  varies almost directly with  $V_{CC}$ ,  $V_{BE1}$  won't vary nearly as much, since the device is exponential. Since  $I_{OUT}$  depends only on  $V_{BE1}$ , the output won't vary much with  $V_{CC}$ .
- Example:

$$V_{CC}=5~{
m V}, R_1=5~{
m k}\Omega, R_2=1~{
m k}\Omega, I_S=1~{
m fA}$$
  $I_{IN}=857~{
m \mu A}, V_{BE1}=715~{
m mV}\Rightarrow I_{OUT}=715~{
m \mu A}$   $V_{CC}'=4.5~{
m V}$   $I_{IN}'=758~{
m \mu A}, V_{BE1}'=710~{
m mV}\Rightarrow I_{OUT}'=710~{
m \mu A}$ 

• Thus, a 10 % change in  $V_{CC}$  results in a 0.7 % change in  $I_{OUT}$ .

## **Self Biasing**

• We can do better than the  $V_{BE}$  referenced source using feedback. What if our source had a current mirror attached that fed back the output current to act as the input current?

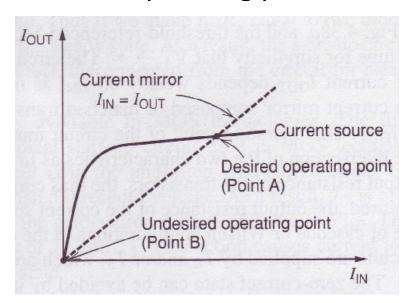


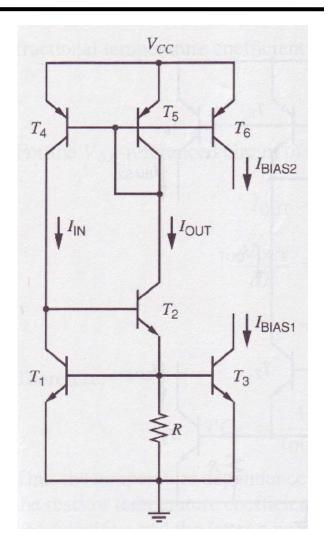
# Self Biasing (cont'd)

- Here, we've attached a *pnp* current mirror to force  $I_{OUT}$  and  $I_{IN}$  to match.
- There are two stable operating points:

$$-I_{IN} = I_{OUT} = 0 \text{ A}$$

Desired operating point



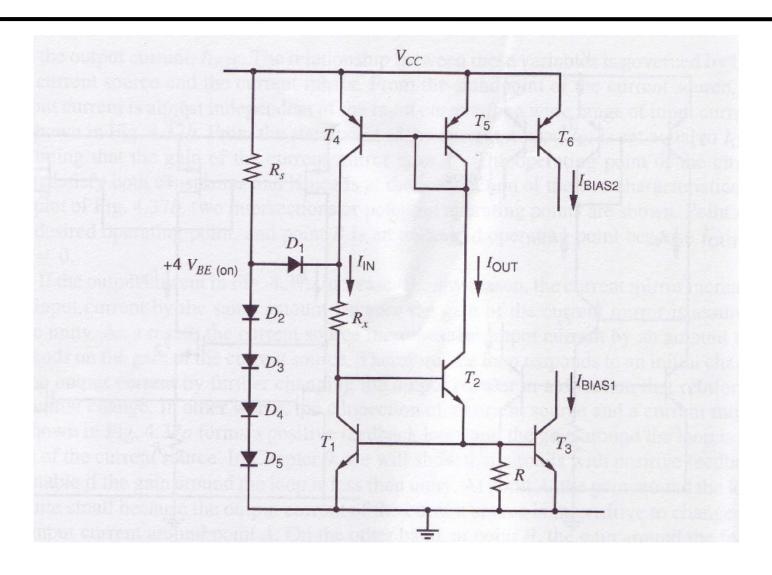


## **Start-up Circuit**

- Need a way to "start-up" the circuit, like a car starter starts up your car.
- Requirements:
  - Must keep the circuit out of the undesired operating point
  - Must not interfere with the circuit once it reaches the desired operating point

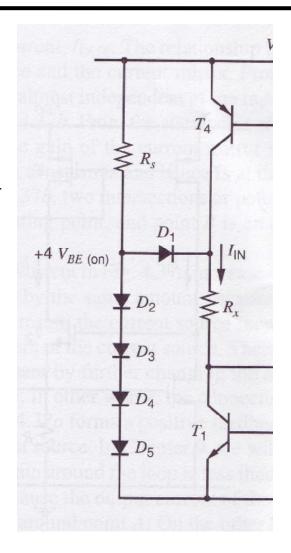
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# Start-up Circuit (cont'd)



# Start-up Circuit (cont'd)

- Let's ensure this works:
  - Assume  $I_{IN} = I_{OUT} = 0$ . This means approximately that  $V_{BE1} = V_{BE2} = 0$ . However, note that the left side of  $D_1$  is four diode drops from ground, meaning  $D_1$  is on. This drops some voltage across  $R_x$ , forcing current to flow into  $T_1$  and  $T_2$ , starting up the circuit.
  - After the circuit is at the desired operating point, turn  $D_1$  off by ensuring  $R_x I_{IN}$  (the drop across  $R_x$ ) is sufficiently large.



### **MOSFET Current Source**

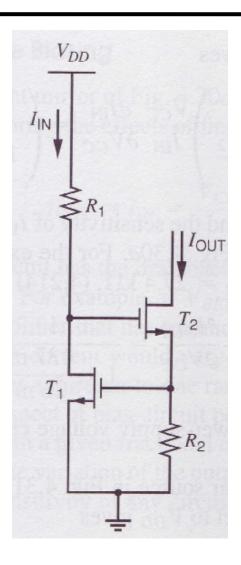
• We can build an analogous circuit from MOSFETs as well. Let's start with a  $V_{TH}$  referenced current source.

$$I_{OUT} = \frac{V_{GS1}}{R_2}$$

$$= \frac{V_{TH} + V_{ov1}}{R_2}$$

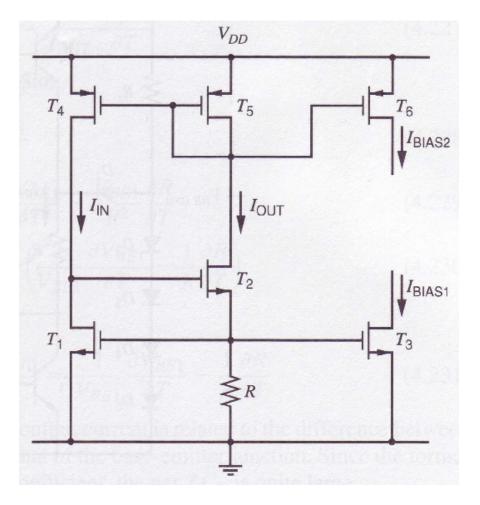
$$= \frac{V_{TH} + \sqrt{\frac{2I_{IN}}{\mu_n C_{ox}(W/L)}}}{R_2}$$

• If we make  $V_{ov1}$  small (by sizing up  $T_1$  or using small currents),  $I_{OUT}$  is controlled primarily by  $V_{TH}$  and  $R_2$ .



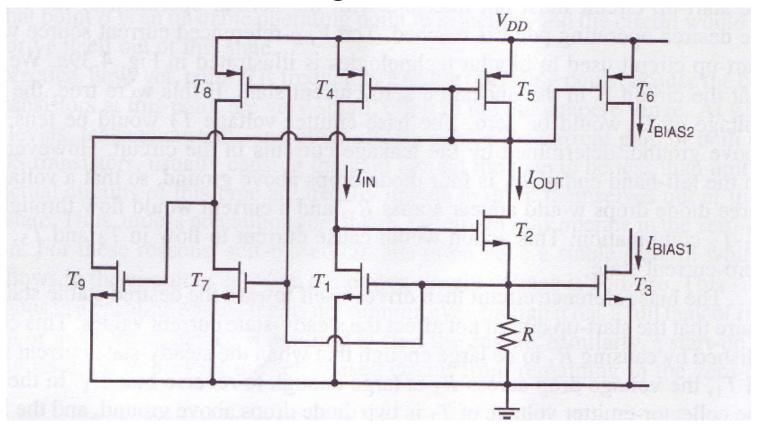
## **MOSFET Current Source (cont'd)**

• Let's add the current mirror feedback.



## **MOSFET Current Source (cont'd)**

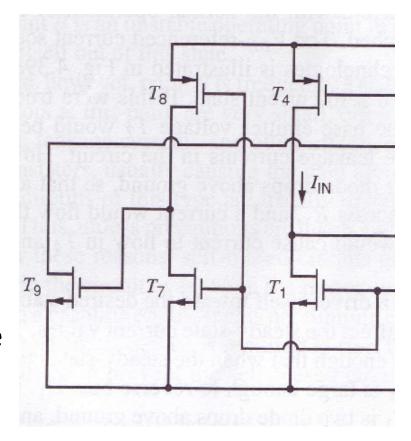
 Finally, the start-up circuitry. It's more typical to use more MOSFETs in MOS technologies rather than diodes.



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## **MOSFET Current Source (cont'd)**

- Assume  $I_{IN} = I_{OUT} = 0$ . This means  $V_{GS1} = 0$ , meaning  $T_8$  is in triode. This turns on  $T_9$  and forces current to flow into  $T_4$  and  $T_5$ .
- Once in steady state, we can size  $T_7$  to ensure that  $T_9$  turns off.  $T_7$  and  $T_8$  don't directly affect the circuit themselves, so the start-up circuit has done its job.



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### References

 Material and figures largely from Analysis and Design of Analog Integrated Circuits, Fourth Edition by Gray, Hurst, Lewis, and Meyer.

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## Guest Lecturer: Prof. Ali Niknejad

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